Vishay Siliconix



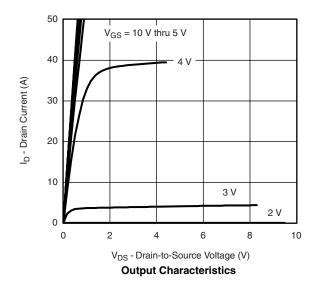
SPECIFICATIONS T _J = 25 °C, unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 1.0			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}$			- 1	μΑ
		V_{DS} = - 32 V, V_{GS} = 0 V, T_{J} = 70 °C			- 10	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 30			Α
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 10.5 A		0.013	0.0155	Ω
		$V_{GS} = -4.5 \text{ V}, I_D = -8.7 \text{ A}$		0.0185	0.0225	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 10.5 A		26		S
Diode Forward Voltage ^a	V_{SD}	I _S = - 2.7 A, V _{GS} = 0 V		- 0.74	- 1.1	V
Dynamic ^b						
Total Gate Charge	Q_g	V _{DS} = - 15 V, V _{GS} = - 5 V, I _D = - 10.5 A		37.5	50	nC
Gate-Source Charge	Q_{gs}			14.3		
Gate-Drain Charge	Q_{gd}			10.7		
Turn-On Delay Time	t _{d(on)}			17	30	
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		18	30	ns
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, V_{GEN} = - 10 V, R_g = 6 Ω		122	190	
Fall Time	t _f			55	85	
Gate Resistance	R_{g}			3.8		Ω
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 2.1 A, dl/dt = 100 A/μs		45		ns

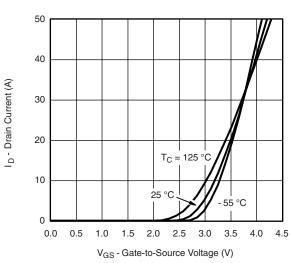
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



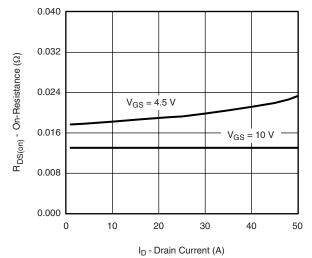


Transfer Characteristics

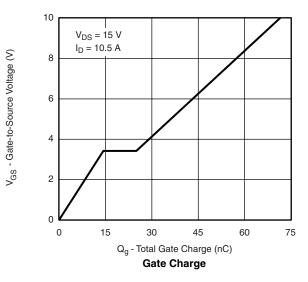


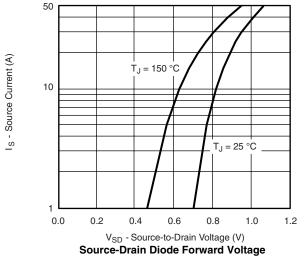


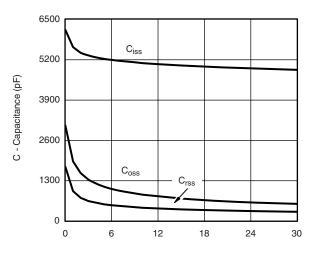
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



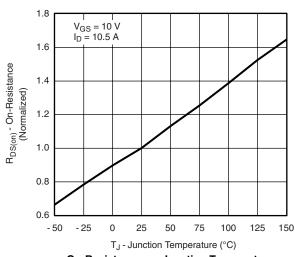
On-Resistance vs. Drain Current



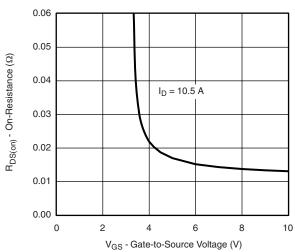




V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



On-Resistance vs. Junction Temperature

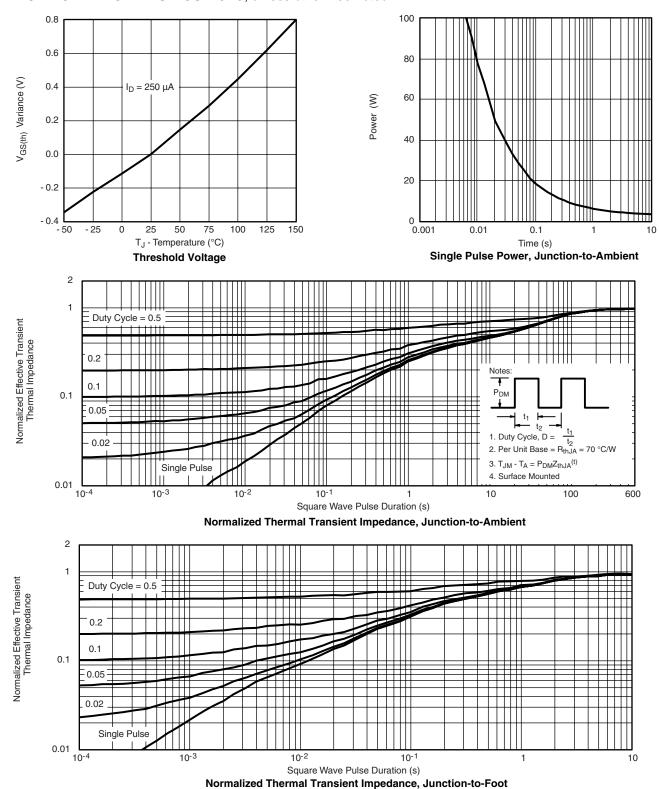


On-Resistance vs. Gate-to-Source Voltage

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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